

# 2 and 4-Channel Low Capacitance ESD Protection Arrays

## CM1224

### Product Description

The CM1224 family of diode arrays has been designed to provide ESD protection for electronic components or subsystems requiring minimal capacitive loading. These devices are ideal for protecting systems with high data and clock rates or for circuits requiring low capacitive loading. Each ESD channel consists of a pair of diodes in series which steer the positive or negative ESD current pulse to either the positive ( $V_P$ ) or negative ( $V_N$ ) supply rail. A Zener diode is embedded between  $V_P$  and  $V_N$ , offering two advantages. First, it protects the  $V_{CC}$  rail against ESD strikes, and second, it eliminates the need for a bypass capacitor that would otherwise be needed for absorbing positive ESD strikes to ground. The CM1224 will protect against ESD pulses up to  $\pm 8$  kV per the IEC 61000-4-2 standard.

These devices are particularly well-suited for protecting systems using high-speed ports such as USB 2.0, IEEE1394 (Firewire<sup>®</sup>, iLink<sup>™</sup>), Serial ATA, DVI, HDMI and corresponding ports in removable storage, digital camcorders, DVD-RW drives and other applications where extremely low loading capacitance with ESD protection are required.

The CM1224 family of devices has lead-free finishing in a small package footprint.

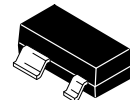
### Features

- Two or Four Channels of ESD Protection
- Provides ESD Protection to IEC61000-4-2 Level 4  $\pm 8$  kV Contact Discharge
- Low Channel Input Capacitance of 0.7 pF Typical
- Minimal Capacitance Change with Temperature and Voltage
- Channel Input Capacitance Matching of 0.02 pF Typical is Ideal for Differential Signals
- Zener Diode Protects Supply Rail and Eliminates the Need for External By-pass Capacitors
- Low Clamping Voltage ( $V_{CLAMP}$ ) at 10 V
- Low Dynamic Resistance ( $R_{DYN}$ ) at 1.08  $\Omega$
- Each I/O Pin Can Withstand Over 1000 ESD Strikes
- Available in SOT and MSOP Lead-free Packages
- These Devices are Pb-Free and are RoHS Compliant

### Applications

- USB2.0 Ports at 480 Mbps in desktop PCs, Notebooks and Peripherals
- IEEE1394 Firewire<sup>®</sup> Ports at 400 Mbps / 800 Mbps
- DVI Ports, HDMI Ports in Notebooks, Set Top Boxes, Digital TVs, LCD Displays
- Serial ATA Ports in Desktop PCs and Hard Disk Drives
- PCI Express Ports

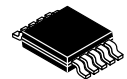
- General Purpose High-speed Data Line ESD Protection



SOT-143  
SR SUFFIX  
CASE 318A

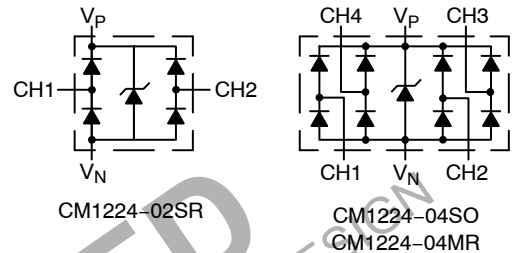


SOT23-6  
SO SUFFIX  
CASE 527AJ

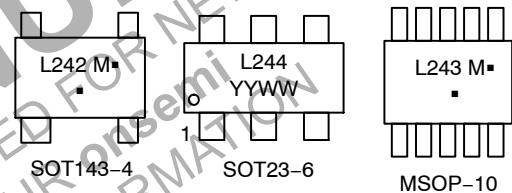


MSOP 10  
MR SUFFIX  
CASE 846AE

### BLOCK DIAGRAM



### MARKING DIAGRAM



L24x = Specific Device Code  
M = Date Code  
YY = Year  
WW = Work Week  
■ = Pb-Free Package  
(Note: Microdot may be in either location)

### ORDERING INFORMATION

Device	Package	Shipping
CM1224-02SR	SOT143-4 (Pb-Free)	3000/Tape & Reel
CM1224-04SO	SOT23-6 (Pb-Free)	3000/Tape & Reel
CM1224-04MR	MSOP-10 (Pb-Free)	4000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

Table 1. PIN DESCRIPTIONS

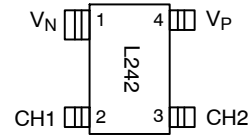
2-Channel, 4-Lead SOT143-4 Package			
Pin	Name	Type	Description
1	V <sub>N</sub>	GND	Negative voltage supply rail
2	CH1	I/O	ESD Channel
3	CH2	I/O	ESD Channel
4	V <sub>P</sub>	PWR	Positive voltage supply rail

4-Channel, 6-Lead SOT23-6 Packages			
Pin	Name	Type	Description
1	CH1	I/O	ESD Channel
2	V <sub>N</sub>	GND	Negative voltage supply rail
3	CH2	I/O	ESD Channel
4	CH3	I/O	ESD Channel
5	V <sub>P</sub>	PWR	Positive voltage supply rail
6	CH4	I/O	ESD Channel

4-Channel, 10-Lead MSOP-10 Packages			
Pin	Name	Type	Description
1	CH1	I/O	ESD Channel
2	NC		No Connect
3	V <sub>P</sub>	PWR	Positive voltage supply rail
4	CH2	I/O	ESD Channel
5	NC		No Connect
6	CH3	I/O	ESD Channel
7	NC		No Connect
8	V <sub>N</sub>	GND	Negative voltage supply rail
9	CH4	I/O	ESD Channel
10	NC		No Connect

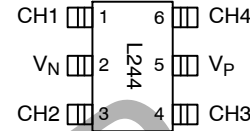
## PACKAGE / PINOUT DIAGRAMS

Top View



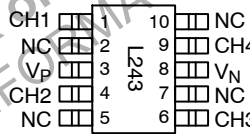
4-Lead SOT143-4

Top View



6-Lead SOT23-6

Top View



10-Lead MSOP-10

## SPECIFICATIONS

Table 2. ABSOLUTE MAXIMUM RATINGS

Parameter	Rating	Units
Operating Supply Voltage (V <sub>P</sub> – V <sub>N</sub> )	6.0	V
Operating Temperature Range	–40 to +85	°C
Storage Temperature Range	–65 to +150	°C
DC Voltage at any Channel Input	(V <sub>N</sub> – 0.5) to (V <sub>P</sub> + 0.5)	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Table 3. STANDARD OPERATING CONDITIONS

Parameter	Rating	Units
Operating Temperature Range	-40 to +85	°C
Package Power Rating SOT23-3, SOT143-4, SOT23-5 and SOT23-6 Packages MSOP-10 Package	225 400	mW

Table 4. ELECTRICAL OPERATING CHARACTERISTICS (Note1)

Symbol	Parameter	Conditions	Min	Typ	Max	Units
$V_P$	Operating Supply Voltage ( $V_P-V_N$ )			3.3	5.5	V
$I_P$	Operating Supply Current	$(V_P-V_N) = 3.3\text{ V}$			8.0	$\mu\text{A}$
$V_F$	Diode Forward Voltage Top Diode Bottom Diode	$I_F = 8\text{ mA}$ ; $T_A = 25^\circ\text{C}$	0.6 0.6	0.8 0.8	0.95 0.95	V
$I_{LEAK}$	Channel Leakage Current	$T_A = 25^\circ\text{C}$ ; $V_P = 5\text{ V}$ , $V_N = 0\text{ V}$		$\pm 0.1$	$\pm 1.0$	$\mu\text{A}$
$C_{IN}$	Channel Input Capacitance	At 1 MHz, $V_P = 3.3\text{ V}$ , $V_N = 0\text{ V}$ , $V_{IN} = 1.65\text{ V}$	0.6	0.7	0.8	pF
$\Delta C_{IN}$	Channel Input Capacitance Matching	At 1 MHz, $V_P = 3.3\text{ V}$ , $V_N = 0\text{ V}$ , $V_{IN} = 1.65\text{ V}$		0.02		pF
$V_{ESD}$	ESD Protection – Peak Discharge Voltage at any channel input, in system Contact discharge per IEC 61000-4-2 standard	$T_A = 25^\circ\text{C}$ (Notes 2 and 3)	$\pm 8$			kV
$V_{CL}$	Channel Clamp Voltage Positive Transients Negative Transients	$T_A = 25^\circ\text{C}$ , $I_{PP} = 1\text{ A}$ , $t_P = 8/20\text{ }\mu\text{S}$ ; (Note 3)		+10 -1.8		V
$R_{DYN}$	Dynamic Resistance Positive Transients Negative Transients	$I_{PP} = 1\text{ A}$ , $t_P = 8/20\text{ }\mu\text{S}$ Any I/O pin to Ground; (Note 3)		1.08 0.66		$\Omega$

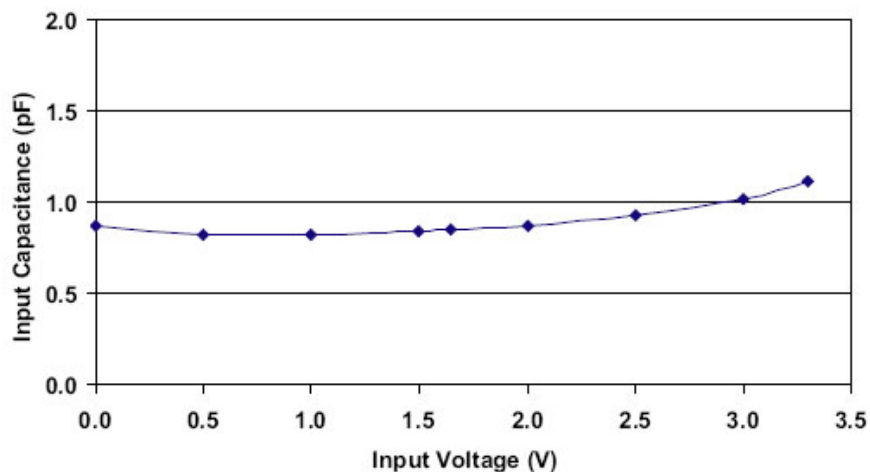
1. All parameters specified at  $T_A = -40^\circ\text{C}$  to  $+85^\circ\text{C}$  unless otherwise noted.

2. Standard IEC 61000-4-2 with  $C_{Discharge} = 150\text{ pF}$ ,  $R_{Discharge} = 330\text{ }\Omega$ ,  $V_P = 3.3\text{ V}$ ,  $V_N$  grounded.

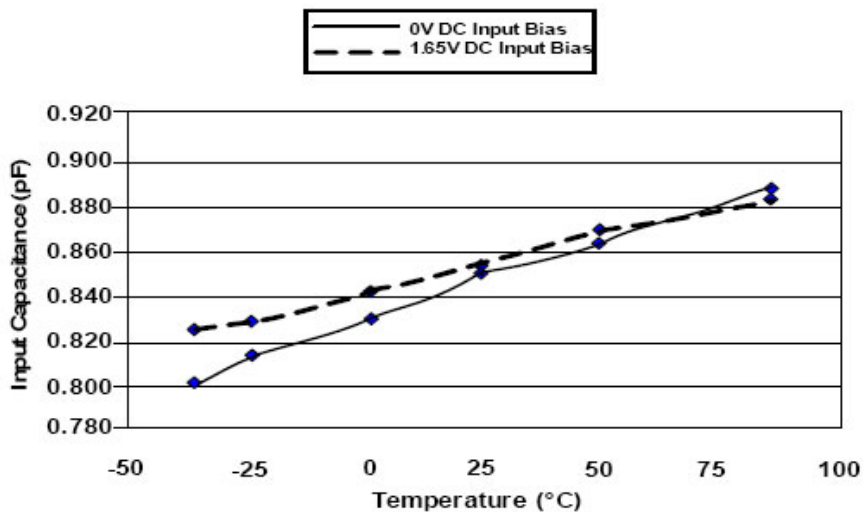
3. These measurements performed with no external capacitor on  $V_P$  ( $V_P$  floating).

## PERFORMANCE INFORMATION

## Input Channel Capacitance Performance Curves

Typical Variation of  $C_{IN}$  vs.  $V_{IN}$ 

( $f=1\text{MHz}$ ,  $V_P = 3.3\text{V}$ ,  $V_N = 0\text{V}$ ,  $0.1\text{ }\mu\text{F}$  chip capacitor between  $V_P$  and  $V_N$ ,  $25^\circ\text{C}$ )

Typical Variation of  $C_{IN}$  vs. Temp

( $f=1\text{MHz}$ ,  $V_{IN}=30\text{mV}$ ,  $V_P = 3.3\text{V}$ ,  $V_N = 0\text{V}$ ,  
 $0.1\text{ }\mu\text{F}$  chip capacitor between  $V_P$  and  $V_N$ )



## APPLICATION INFORMATION

## Design Considerations

To realize the maximum protection against ESD pulses, care must be taken in the PCB layout to minimize parasitic series inductances on the Supply/ Ground rails as well as the signal trace segment between the signal input (typically a connector) and the ESD protection device. Figure 3 illustrates an example of a positive ESD pulse striking an input channel. The parasitic series inductance back to the power supply is represented by  $L_1$  and  $L_2$ . The voltage  $V_{CL}$  on the line being protected is:

$$V_{CL} = \text{Fwd voltage drop of } D_1 + V_{\text{SUPPLY}} + L_1 \times d(I_{\text{ESD}}) / dt + L_2 \times d(I_{\text{ESD}}) / dt$$

where  $I_{\text{ESD}}$  is the ESD current pulse, and  $V_{\text{SUPPLY}}$  is the positive supply voltage.

An ESD current pulse can rise from zero to its peak value in a very short time. As an example, a level 4 contact discharge per the IEC61000-4-2 standard results in a current pulse that rises from 0 to 30 Amps in 1ns. Here  $d(I_{\text{ESD}})/dt$  can be approximated by  $\Delta I_{\text{ESD}}/\Delta t$ , or  $30/(1 \times 10^{-9})$ . So just 10 nH of series inductance ( $L_1$  and  $L_2$  combined) will lead to a 300 V increment in  $V_{CL}$ !

Similarly for negative ESD pulses, parasitic series inductance from the  $V_N$  pin to the ground rail will lead to drastically increased negative voltage on the line being protected.

The CM1224 has an integrated Zener diode between  $V_P$  and  $V_N$ . This greatly reduces the effect of supply rail inductance  $L_2$  on  $V_{CL}$  by clamping  $V_P$  at the breakdown voltage of the Zener diode. However, for the lowest possible  $V_{CL}$ , especially when  $V_P$  is biased at a voltage significantly below the Zener breakdown voltage, it is recommended that a 0.22  $\mu\text{F}$  ceramic chip capacitor be connected between  $V_P$  and the ground plane.

As a general rule, the ESD Protection Array should be located as close as possible to the point of entry of expected electrostatic discharges. The power supply bypass capacitor mentioned earlier should be as close to the  $V_P$  pin of the Protection Array as possible, with minimum PCB trace lengths to the power supply, ground planes and between the signal input and the ESD device to minimize stray series inductance.

## Additional Information

See also ON Semiconductor Application Note "Design Considerations for ESD Protection".

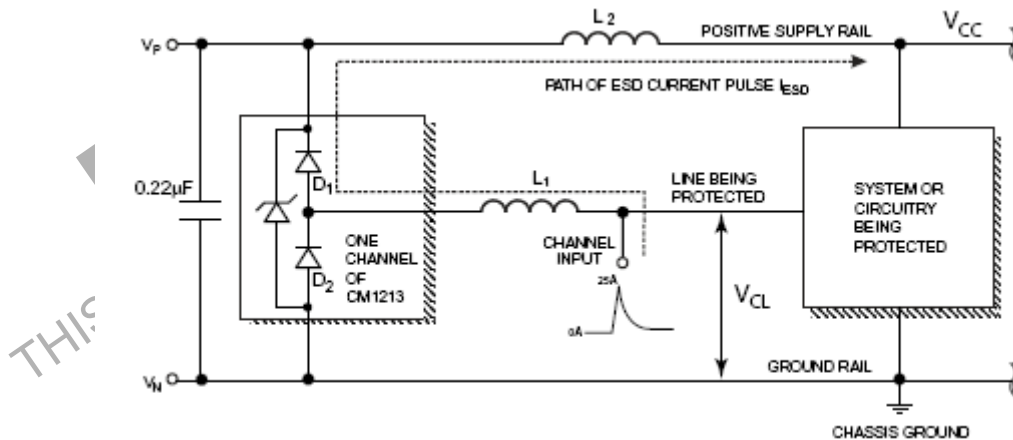


Figure 3. Application of Positive ESD Pulse between Input Channel and Ground

# CM1224

## MECHANICAL DETAILS

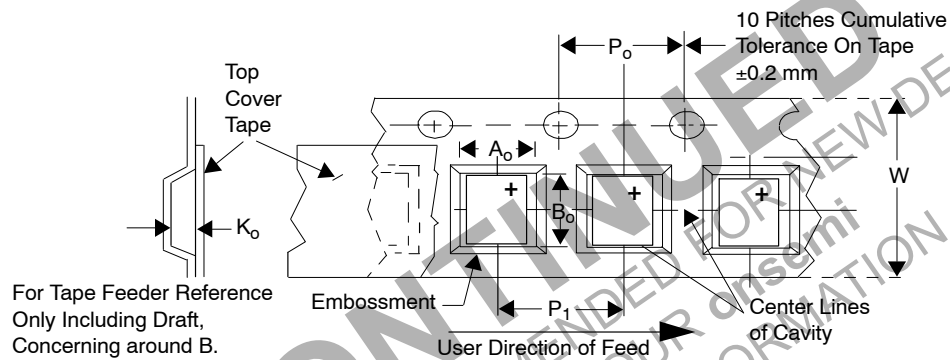
The CM1224 is available in SOT143-4, SOT23-6 and MSOP-10 packages with lead-free finishing. The various package drawings are presented below.

### SOT143-4, SOT23-6 and MSOP-10 Mechanical Specifications

The CM1224-02SR devices are supplied in 4-pin SOT143 packages, the CM1224-04SO devices are packaged in 6-pin SOT23 and the CM1224-04MR in 10-lead MSOP packages. Dimensions are presented below.

**Table 5. TAPE AND REEL SPECIFICATIONS**

Part Number	Chip Size (mm)	Pocket Size (mm) $B_0 \times A_0 \times K_0$	Tape Width W	Reel Diameter	Qty per Reel	$P_0$	$P_1$
CM1224-02SR	2.92 X 2.37 X 1.01	2.60 X 3.15 X 1.20	8 mm	178 mm (7")	3000	4 mm	4 mm
CM1224-04SO	2.90 X 2.80 X 1.45	3.20 X 3.20 X 1.40	8 mm	178 mm (7")	3000	4 mm	4 mm
CM1224-04MR	3.00 X 3.00 X 0.85	3.30 X 5.30 X 1.30	12 mm	330 mm (13")	4000	4 mm	8 mm



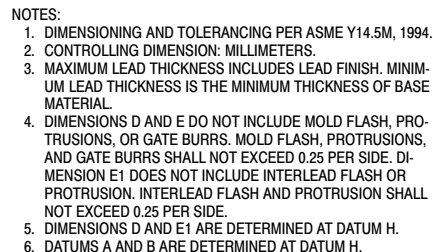
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FireWire is a registered trademark of Apple Computer, Inc.



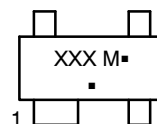
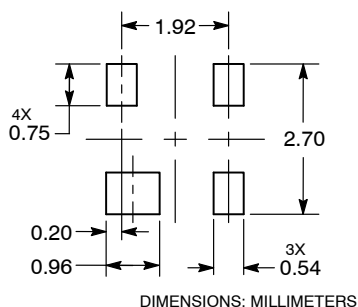


## DATE 07 SEP 2011



DIM	MILLIMETERS	
	MIN	MAX
A	0.80	1.12
A1	0.01	0.15
b	0.30	0.51
b1	0.76	0.94
c	0.08	0.20
D	2.80	3.05
E	2.10	2.64
E1	1.20	1.40
e	1.92 BSC	
e1	0.20 BSC	
L	0.35	0.70
l2	0.25 BSC	

### GENERIC MARKING DIAGRAM\*



XXX = Specific Device Code  
M = Date Code  
▪ = Pb-Free Package

(Note: Microdot may be in either location)

\*This information is generic. Please refer to device data sheet for actual part marking.  
Pb-Free indicator, "G" or microdot "▪", may or may not be present.

- |                  |               |               |               |               |            |
|------------------|---------------|---------------|---------------|---------------|------------|
| STYLE 1:         | STYLE 2:      | STYLE 3:      | STYLE 4:      | STYLE 5:      | STYLE 6:   |
| PIN 1. COLLECTOR | PIN 1. SOURCE | PIN 1. GROUND | PIN 1. OUTPUT | PIN 1. SOURCE | PIN 1. GND |
| 2. EMITTER       | 2. DRAIN      | 2. SOURCE     | 2. GROUND     | 2. DRAIN      | 2. RF IN   |
| 3. EMITTER       | 3. GATE 1     | 3. INPUT      | 3. GROUND     | 3. GATE 1     | 3. VREG    |
| 4. BASE          | 4. GATE 2     | 4. OUTPUT     | 4. INPUT      | 4. SOURCE     | 4. RF OUT  |
|                  |               |               |               |               |            |
| STYLE 7:         | STYLE 8:      | STYLE 9:      | STYLE 10:     | STYLE 11:     |            |
| PIN 1. SOURCE    | PIN 1. SOURCE | PIN 1. GND    | PIN 1. DRAIN  | PIN 1. SOURCE |            |
| 2. GATE          | 2. GATE       | 2. IOUT       | 2. N/C        | 2. GATE 1     |            |
| 3. DRAIN         | 3. DRAIN      | 3. VCC        | 3. SOURCE     | 3. GATE 2     |            |
| 4. SOURCE        | 4. N/C        | 4. VREF       | 4. GATE       | 4. DRAIN      |            |

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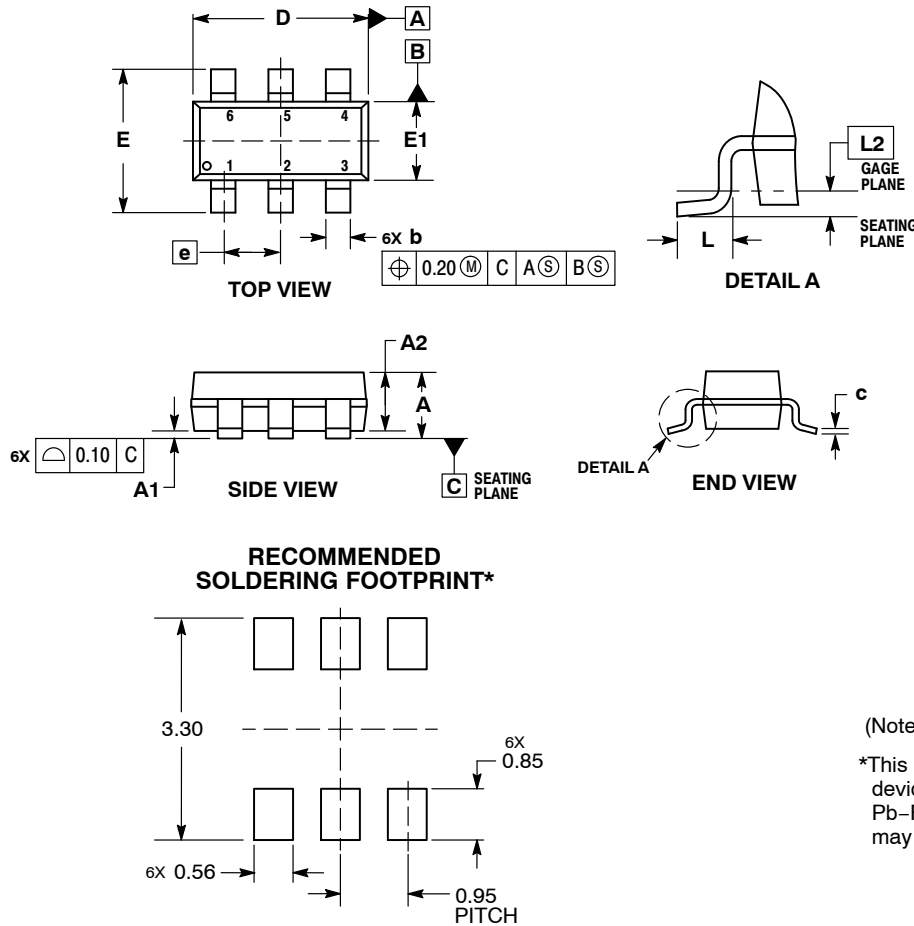




SCALE 2:1

**SOT-23, 6 Lead**  
**CASE 527AJ**  
**ISSUE B**

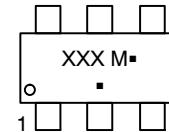
DATE 29 FEB 2012



## NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DATUM C IS THE SEATING PLANE.

MILLIMETERS		
DIM	MIN	MAX
A	---	1.45
A1	0.00	0.15
A2	0.90	1.30
b	0.20	0.50
c	0.08	0.26
D	2.70	3.00
E	2.50	3.10
E1	1.30	1.80
e	0.95 BSC	
L	0.20	0.60
L2	0.25 BSC	

**GENERIC MARKING DIAGRAM\***


XXX = Specific Device Code  
M = Date Code  
▪ = Pb-Free Package

(Note: Microdot may be in either location)

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present.

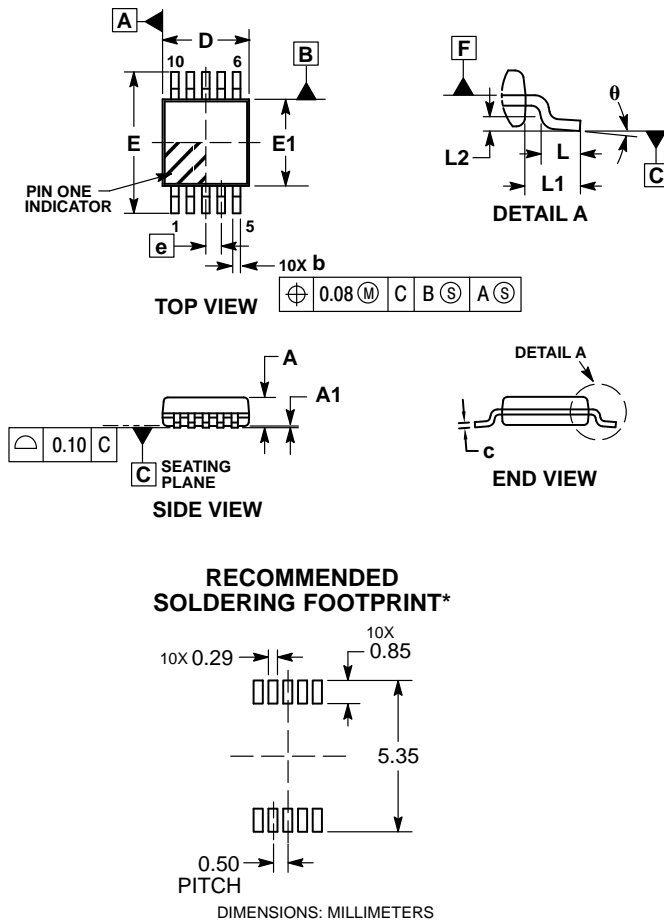
\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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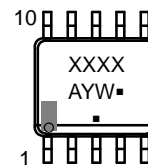
  
**SCALE 1:1**
**MSOP10, 3x3**  
**CASE 846AE**  
**ISSUE A**

DATE 20 JUN 2017


**NOTES:**

1. DIMENSIONS AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSIONS: MILLIMETERS.
3. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.10 MM IN EXCESS OF MAXIMUM MATERIAL CONDITION.
4. DIMENSION D DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 MM PER SIDE. DIMENSION E DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 MM PER SIDE. DIMENSIONS D AND E ARE DETERMINED AT DATUM F.
5. DATUMS A AND B TO BE DETERMINED AT DATUM F.
6. A1 IS DEFINED AS THE VERTICAL DISTANCE FROM THE SEATING PLANE TO THE LOWEST POINT ON THE PACKAGE BODY.

DIM	MILLIMETERS		
	MIN	NOM	MAX
A	—	—	1.10
A1	0.00	0.05	0.15
A2	0.75	0.85	0.95
b	0.17	—	0.27
c	0.13	—	0.23
D	2.90	3.00	3.10
E	4.75	4.90	5.05
E1	2.90	3.00	3.10
e	0.50 BSC		
L	0.40	0.70	0.80
L1	0.95 REF		
L2	0.25 BSC		
θ	0°	—	8°

**GENERIC MARKING DIAGRAM\***


XXXX = Specific Device Code  
A = Assembly Location  
Y = Year  
W = Work Week  
▪ = Pb-Free Package

(Note: Microdot may be in either location)

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present and may be in either location. Some products may not follow the Generic Marking.

\*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERM/D.

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<b>DESCRIPTION:</b>	<b>MSOP10, 3X3</b>	<b>PAGE 1 OF 1</b>

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